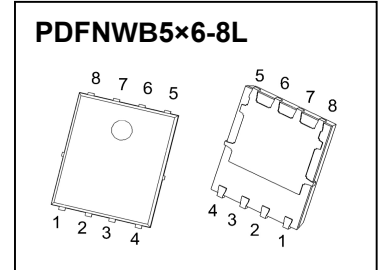


CJAC35N03 N-Channel Power MOSFET

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
30 V	7mΩ@10V	35A
	12mΩ@4.5V	


DESCRIPTION

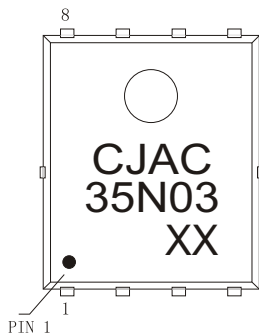
The CJAC35N03 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications

FEATURES

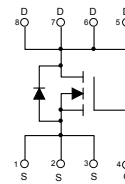
- High density cell design for ultra low $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

APPLICATIONS

- High side switch in POL DC/DC converter
- Secondary side synchronous rectifier

MARKING


CJAC35N03 = Part No.
Solid dot=Pin1 indicator
XX=Code

EQUIVALENT CIRCUIT

ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	±20	
Continuous Drain Current	$I_D^{①}$	35	A
Pulsed Drain Current	$I_{DM}^{②}$	120	
Maximum Power Dissipation	$P_D^{①}$	125	W
Single Pulsed Avalanche Energy	$E_{AS}^{③}$	150	mJ
Thermal Resistance from Junction to Case	$R_{\theta JC}^{①}$	1	°C/W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}^{⑥}$	62.5	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55~ +150	
Lead Temperature for Soldering Purposes(1/8" from case for 10s)	T_L	260	

MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	V _{(BR) DSS}	V _{GS} = 0V, I _D =250uA	30			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =30V, V _{GS} =0V			1	μA
Gate-body leakage current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
On characteristics ④						
Gate-threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0	1.4	3.0	V
Static drain-source on-sate resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =10A		8.0	12	mΩ
		V _{GS} =10V, I _D =12A		5.3	7	mΩ
Dynamic characteristics ④ ⑤						
Input capacitance	C _{iSS}	V _{DS} =15V,V _{GS} =0V, f =1MHz		2013		pF
Output capacitance	C _{oSS}			257		
Reverse transfer capacitance	C _{rSS}			228		
Gate resistance	R _g	f =1MHz		2.1		Ω
Switching characteristics ④ ⑤						
Total gate charge	Q _g	V _{GS} =10V, V _{DS} =15V, I _D =12A		40		nC
Gate-source charge	Q _{gs}			5.1		
Gate-drain charge	Q _{gd}			9.1		
Turn-on delay time	t _{d(on)}	V _{DS} =15V,I _D =12A , V _{GS} =10V,R _G =6Ω		9		ns
Turn-on rise time	t _r			26		
Turn-off delay time	t _{d(off)}			35		
Turn-off fall time	t _f			8		
Drain-Source Diode Characteristics						
Drain-source diode forward voltage	V _{SD} ④	V _{GS} =0V, I _S =12A			1.2	V
Continuous drain-source diode forward current	I _S ①				35	A
Pulsed drain-source diode forward current	I _{SM} ②				120	A

Notes:

1. $T_C=25^{\circ}\text{C}$ Limited only by maximum temperature allowed.

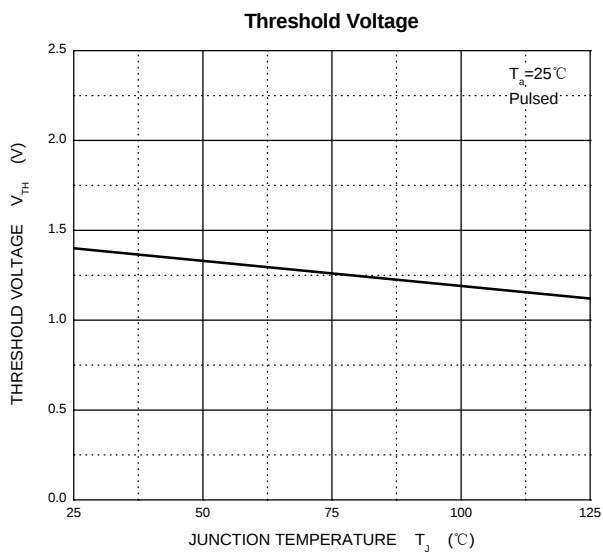
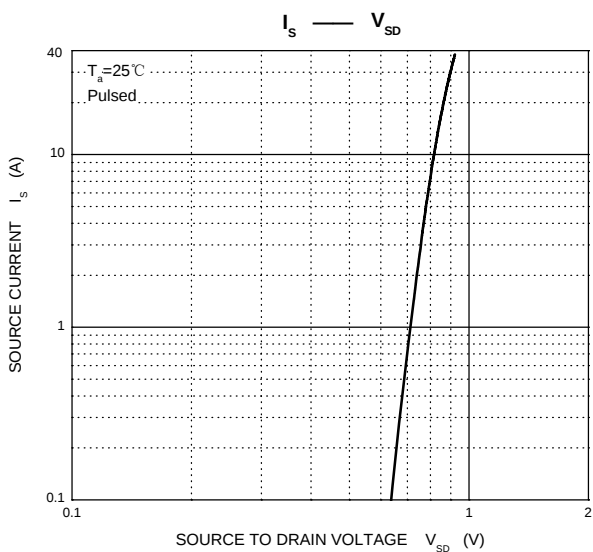
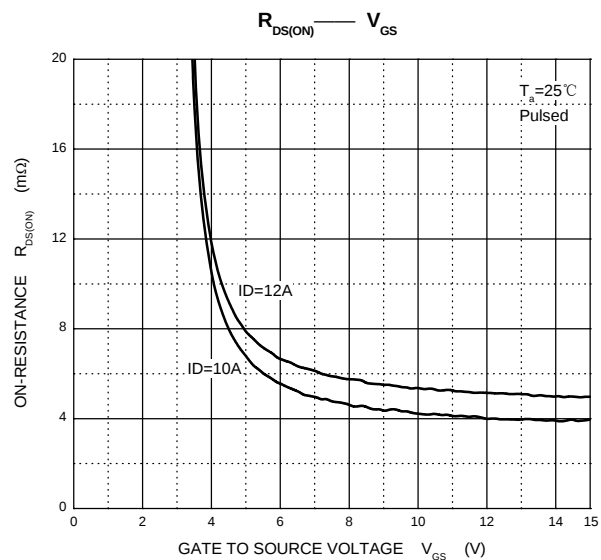
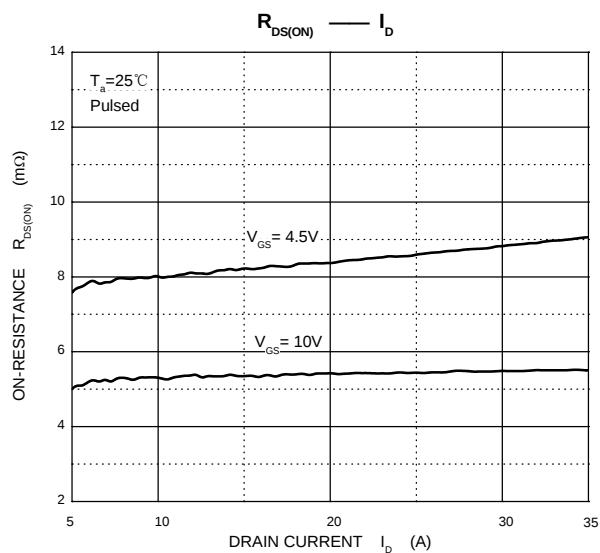
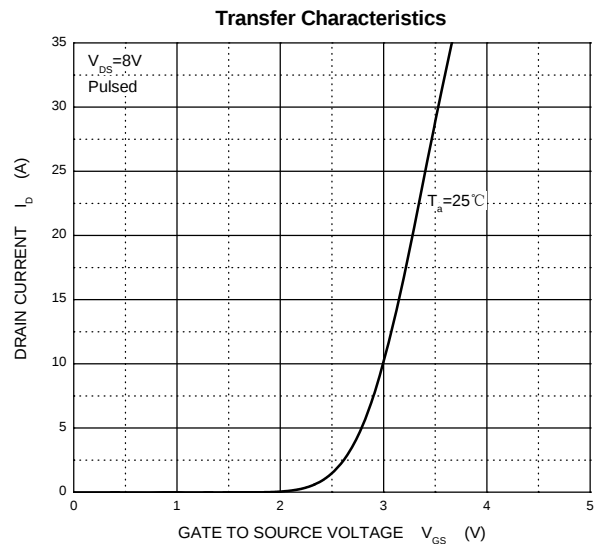
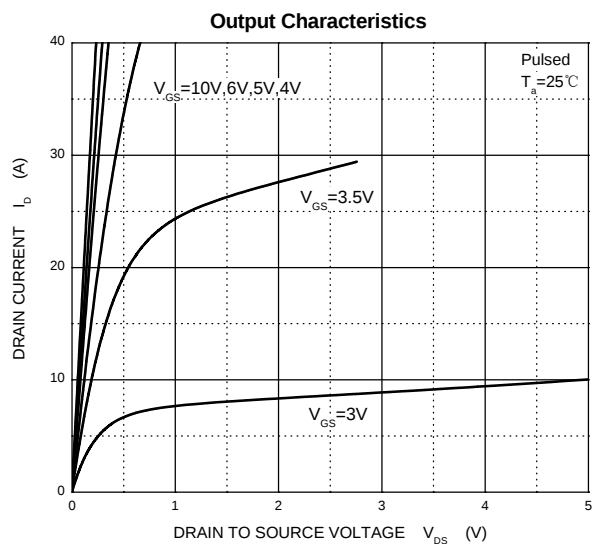
2. $P_{W}\leq 10\mu s$, Duty cycle $\leq 1\%$.

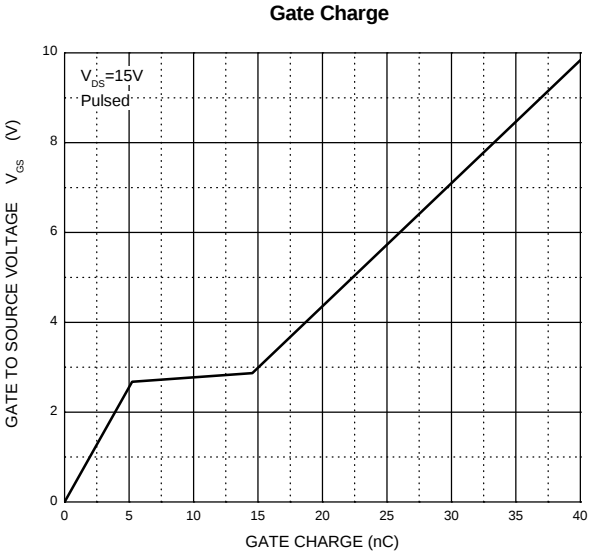
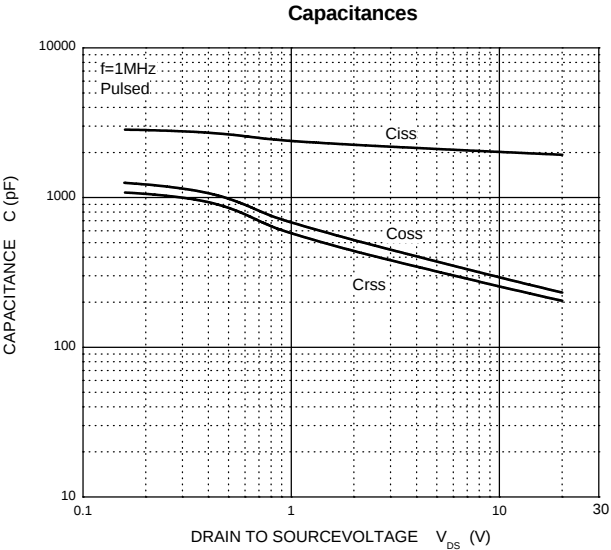
3. EAS condition: $V_{DD}=15V, V_{GS}=10V, L=0.1mH, R_g=25\Omega$ Starting $T_J=25^{\circ}\text{C}$.

4. Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.

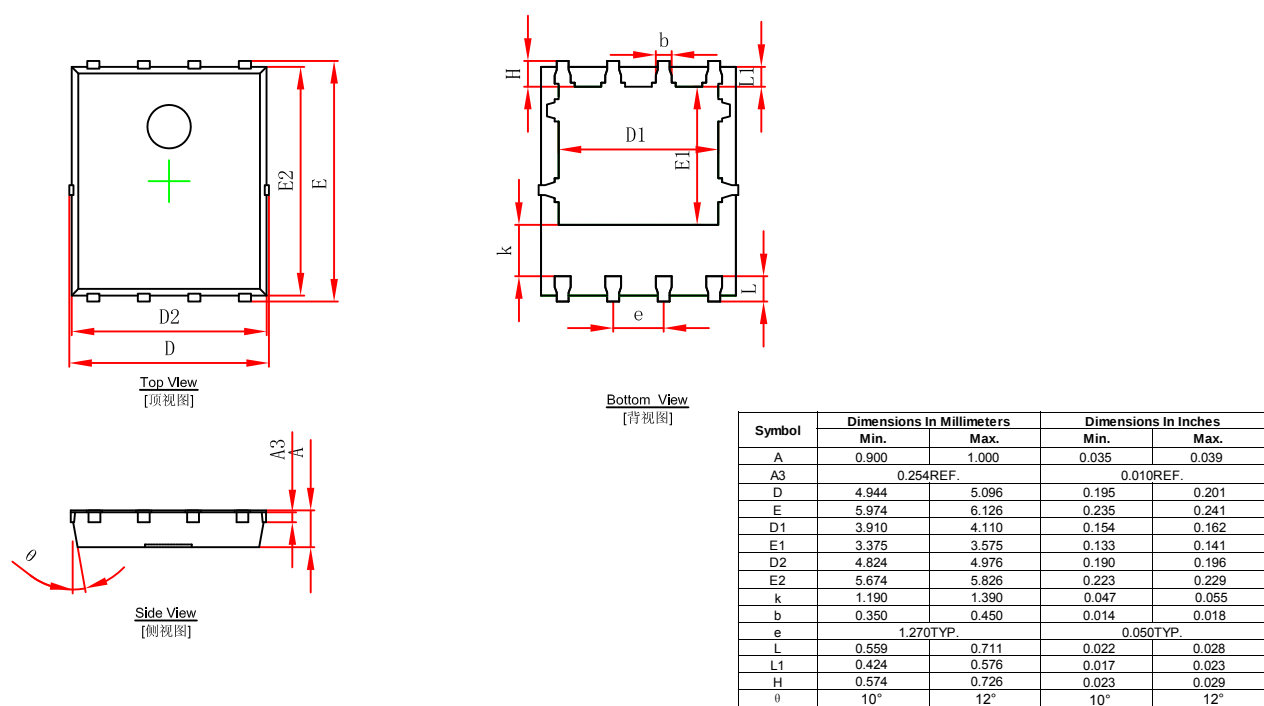
5. Guaranteed by design, not subject to production.

6. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with $T_a=25^{\circ}\text{C}$.

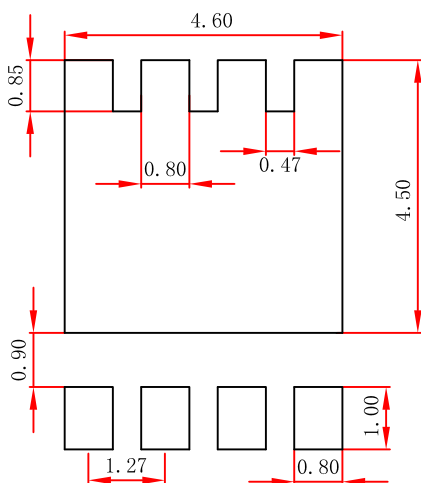




PDFNWB5x6-8L Package Outline Dimensions



PDFNWB5x6-8L Suggested Pad Layout



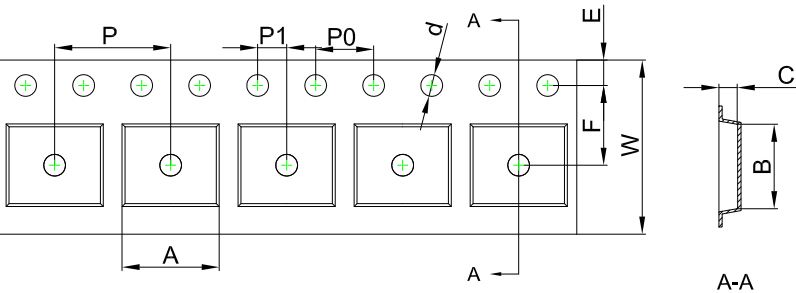
- Note:
- 1.Controlling dimension:in millimeters.
 - 2.General tolerance:±0.05mm.
 - 3.The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

PDFNWB5×6 Tape and Reel

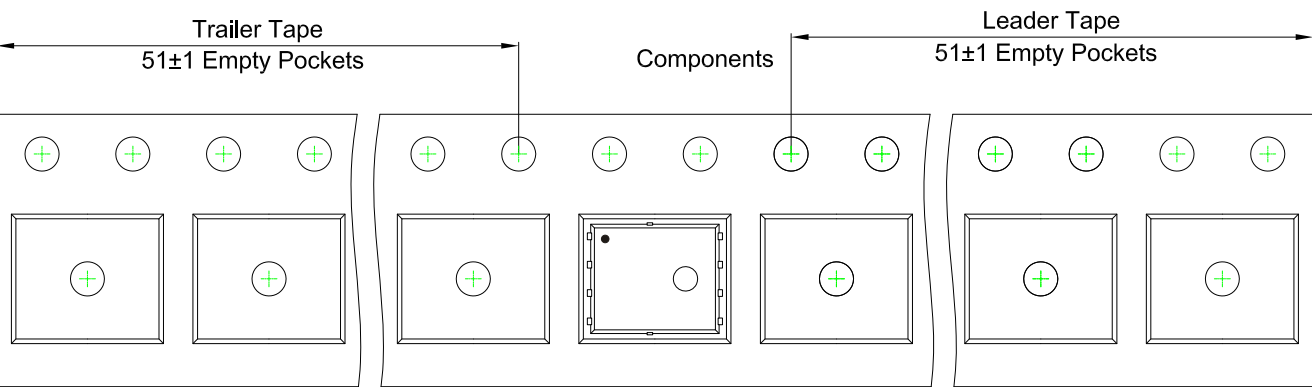
PDFNWB5×6-8L Embossed Carrier Tape



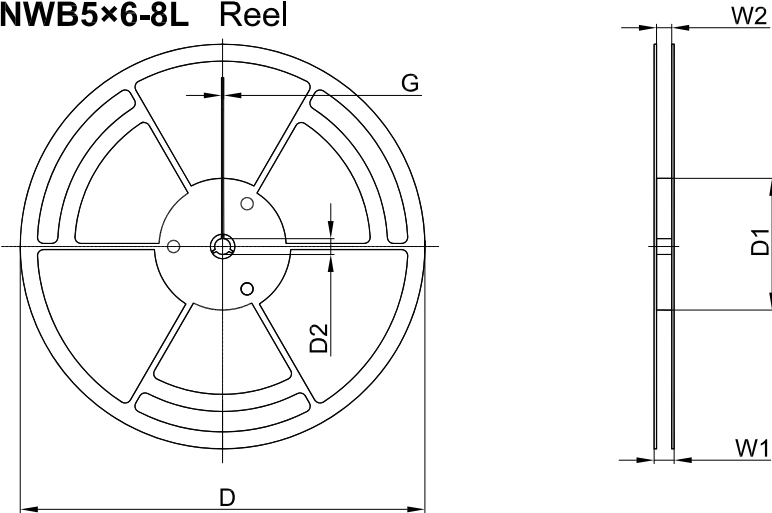
Packaging Description:
PDFNWB5×6-8L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
PDFNWB5×6-8L	6.30	5.30	1.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

PDFNWB5×6-8L Tape Leader and Trailer



PDFNWB5×6-8L Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	G	W1	W2
13"Dia	Ø330.00	100.00	13.00	1.90	17.60	12.40

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
5,000 pcs	13 inch	5,000 pcs	340×336×29	50,000 pcs	353×346×365